Toshiba Intelligent Power Device Silicon Monolithic Power MOS Integrated Circuit

# **TPD1032F**

2-IN-1 Low-Side Power Switch for Motor, Solenoid and Lamp Drive

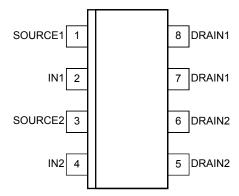
The TPD1032F is a 2-IN-1 low-side switch.

The IC has a vertical MOSFET output which can be directly driven from a CMOS or TTL logic circuit (e.g., an MPU). The IC is equipped with intelligent self-protection functions.

#### Features

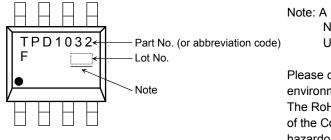
- Two built-in power IC chips with a new structure combining a control block and a vertical power MOSFET (L<sup>2</sup>- $\pi$ -MOS) on each chip.
- Can directly drive a power load from a CMOS or TTL logic.
- Built-in protection circuits against overvoltage (active clamp), overtemperature (thermal shutdown), and overcurrent (current limiter).
- Low Drain-Source ON-resistance:  $R_{DS}(ON) = 0.4 \Omega (max) (@V_{IN} = 5 V, I_D = 1 A, T_{ch} = 25^{\circ}C)$
- Low Leakage Current:  $I_{DSS} = 10 \ \mu A \ (max) \ (@V_{IN} = 0 \ V, V_{DS} = 20 \ V, T_{ch} = 25^{\circ}C)$
- Low Input Current: IIN = 300  $\mu$ A (max) (@VIN = 5 V, T<sub>ch</sub> = -40 $\sim$ 110°C)
- 8-pin SOP package for surface with embossed-tape packing.

#### Pin Assignment (top view)



Due to its MOS structure, this product is sensitive to static electricity.

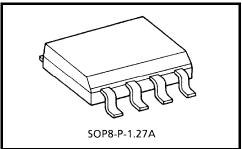
#### Marking



Note: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

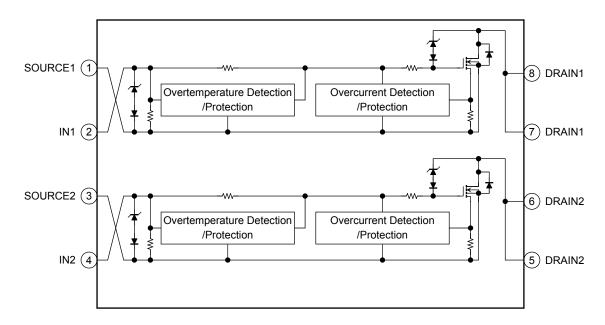
Start of commercial production 1999-10



Weight: 0.08 g (typ.)

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#### **Block Diagram**

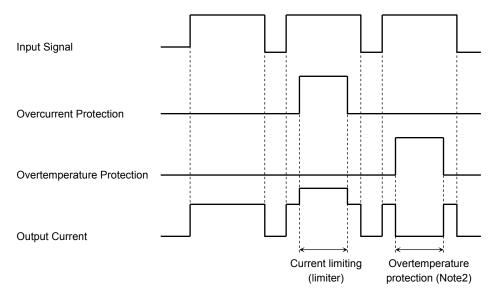


#### **Pin Description**

Pin No.	Symbol	Pin Description
1	SOURCE1	Source pin 1
	IN1	Input pin 1
2		This pin is connected to a pull-down resistor internally, so that even when input wiring is open-circuited, output can never be turned on inadvertently.
3	SOURCE2	Source pin 2
	IN2	Input pin 2
4		This pin is connected to a pull-down resistor internally, so that even when input wiring is open-circuited, output can never be turned on inadvertently.
E G	DRAIN2	Drain pin 2
5, 6		Drain current is limited (by current limiter) if it exceeds 3 A (min) in order to protect the IC.
7 0	DRAIN1	Drain pin 1
7, 8		Drain current is limited (by current limiter) if it exceeds 3 A (min) in order to protect the IC.

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#### **Timing Chart**



Note2: The overheating detector circuits feature hysteresis. After overheating is detected, normal operation is restored only when the channel temperature falls by the hysteresis amount (5°C typ.) in relation to the overheating detection temperature.

#### **Truth Table**

IN	V <sub>OUT</sub>	Mode		
L	Н	Normal		
Н	L	Normai		
L	Н	Overcurrent		
Н	Н	Overcuitent		
L	Н	Overtemperature		
Н	Н	Overtemperature		

Absolute Maximum Ratings (Ta = 25°C)

	Characteristics			Rating	Unit	
Drain agurag valtaga		DC		20	M	
Drain-source voltage		Pulse	∨DS	40	v	
Drain current			I <sub>D</sub>	Internally limited	А	
Input voltage			V <sub>IN</sub>	-0.3 to 7	V	
Power dissipation		gle-device operation (Note4a)	P <sub>D(1)</sub>	0.95		
(Ta=25°C)(Note 3a)		gle-device value at dual eration (Note4b)	P <sub>D(2)</sub>	0.54	107	
Power dissipation	Sin	gle-device operation (Note4a)	P <sub>D(3)</sub>	20         V           40         V           ID         Internally limited         A $V_{IN}$ -0.3 to 7         V           D(1)         0.95         V           D(2)         0.54         W           D(3)         0.38         W           EAS         90         mJ           AR         3         A           Copr         -40 to 110         °C           Tch         150         °C	vv	
(Ta=25°C)(Note 3b)		gle-device value at dual eration (Note4b)	P <sub>D(4)</sub>			
Single pulse active clamp capability (Note 5)		E <sub>AS</sub>	90	mJ		
Active clamp current			I <sub>AR</sub>	3	А	
Repetitive active clamp capability (Note 6)			E <sub>AR</sub>	54	μJ	
Operating temperature	arating temperature		T <sub>opr</sub>	-40 to 110	°C	
Channel temperature	nel temperature		T <sub>ch</sub>	150 °C		
Storage temperature			T <sub>stg</sub>	–55 to 150	°C	

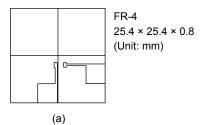
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Thermal Characteristics**

C	Symbol	Max	Unit			
Thermal resistance, to ambient	channel (Note3a)	Single-device operation (Note 4a)	R <sub>th (ch-a)(1)</sub>	132	°C/W	
		Single-device value at dual operation (Note 4b)	R <sub>th (ch-a)(2)</sub>	231	0/10	
Thermal resistance, to ambient	channel (Note3b)	Single-device operation (Note 4a)	R <sub>th (ch-a)(1)</sub>	330	°C/W	
		Single-device value at dual operation (Note 4b)	R <sub>th (ch-a)(2)</sub>	625		

Note 3:





FR-4 25.4 × 25.4 × 0.8 (Unit: mm)



b) Device mounted on a glass-epoxy board (b)

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Note 4:

- a) The power dissipation and thermal resistance values are shown for a single device. (During single-device operation, power is only applied to one device.)
- b) The power dissipation and thermal resistance values are shown for a single device. (During dual operation, power is evenly applied to both device.)

Note 5: Active clamp capability (single pulse) test condition

 $V_{DD}$  = 25 V, Starting T<sub>ch</sub> = 25°C, L = 10 mH, I<sub>AR</sub> = 3 A, R<sub>G</sub> = 25  $\Omega$ 

Note 6: Repetitive rating, pulse width limited by maximum channel temperature.

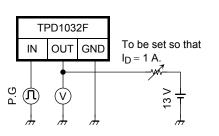
#### **Electrical Characteristics**

Characteristics	Symbol	Test Circuit	Te	est Condition	Min	Тур.	Max	Unit
Drain-source clamp voltage	V (CL) DSS	_	T <sub>ch</sub> =-40∼110°C	V <sub>IN</sub> = 0 V, I <sub>D</sub> =1mA	40	_	60	V
Input threshold voltage	V <sub>th</sub>		T <sub>ch</sub> =25°C	V <sub>DS</sub> = 13 V, I <sub>D</sub> =10mA	1.0	_	2.8	V
input threshold voltage			T <sub>ch</sub> =-40~110°C		0.9	_	3.0	
Protective circuit operation			T <sub>ch</sub> =25°C	—	3	_	7	v
input voltage range	V <sub>IN (opr)</sub>	_	T <sub>ch</sub> =-40∼110°C	—	3.5	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	v	
Drain out off ourrant			T <sub>ch</sub> =25°C		_	.0       —       2.8 $0.9$ — $3.0$ $3$ — $7$ $3.5$ — $7$ $0.5$ — $7$ $0.5$ — $7$ $0.5$ — $7$ $-$ — $100$ $-$ — $100$ $-$ — $300$ $-$ — $300$ $-$ — $350$ $-$ — $0.6$ $50$ $160$ — $3.7$ — $2$ $  30$ $  30$ $  30$ $  30$ $  30$ $  60$ $  60$	_	
Drain cut-off current	IDSS	_	T <sub>ch</sub> =-40~110°C	V <sub>IN</sub> = 0 V, V <sub>DS</sub> =20V	_	_	100	μA
Input current	I <sub>IN (1)</sub>		T <sub>ch</sub> =25°C	V <sub>IN</sub> = 5 V, at normal operation			300	μA
	l <sub>IN (2)</sub>	_	T <sub>ch</sub> =-40∼110°C	V <sub>IN</sub> = 5 V, when overcurrent protective circuit is actuated	_	_	350	
Drain-source on resistance	<b>D</b>		T <sub>ch</sub> =25°C	V	_	0.25	0.4	Ω
Drain-source on resistance	R <sub>DS (ON)</sub>	_	T <sub>ch</sub> =-40~110°C	V <sub>IN</sub> = 5 V, I <sub>D</sub> = 1 A	40 $60$ $1.0$ $2.8$ $0.9$ $3.0$ $3$ $7$ $3.5$ $7$ $3.5$ $7$ $$ $10$ $$ $100$ $$ $100$ $$ $300$ $$ $300$ $$ $0.25$ $$ $0.6$ $150$ $160$ $3$ $3.7$ $2$ $$ $30$ $$ $60$ $$ $60$ $$ $60$ $$ $$	52		
Overtemperature protection	Τ <sub>S</sub>			$V_{IN} = 5 V$	150	160	_	°C
Overcurrent protection	la		T <sub>ch</sub> =25°C	V <sub>IN</sub> = 5 V	3	3.7		A
Overcurrent protection	IS		$T_{ch}$ =-40~110°C	VIN – 5 V	2			
	t <sub>ON</sub>		T <sub>ch</sub> =25°C	V <sub>DD</sub> = 13 V, V <sub>IN</sub> = 0V/5 V, I <sub>D</sub> = 1 A			30	μs
Switching time		1	T <sub>ch</sub> =-40~110°C		_	_	60	
	tOFF		T <sub>ch</sub> =25°C		_	_	60	
			T <sub>ch</sub> =-40~110°C				90	
Source-drain diode forward voltage	V <sub>DSF</sub>		T <sub>ch</sub> =25°C	I <sub>F</sub> = 3 A, V <sub>IN</sub> = 0 V			1.7	V

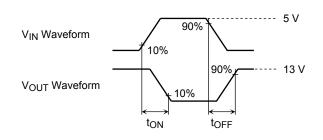
#### **Test Circuit 1**

Switching time measuring circuit

#### **Test Circuit**



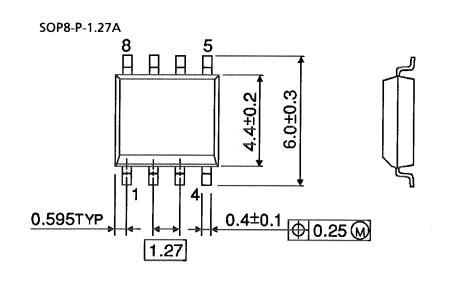
#### **Measured Waveforms**

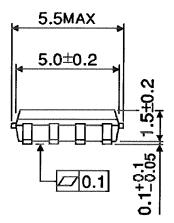


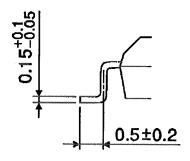
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Unit : mm

### Package Dimensions







Weight: 0.08 g (typ.)

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